

2SK1475

Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

Package Dimensions

unit:mm



unit:mm



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SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		100	V
Gate-to-Source Voltage	V _{GSS}		±15	V
Drain Current (DC)	۱D		8	A
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	32	A
Allowable Power Dissipation	PD	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			1.1 14
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	100			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	IG=±100µA, V _{DS} =0	±15			V
Zero-Gate Votlage Drain Current	IDSS	V _{DS} =100V, V _{GS} =0			100	μA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±12V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0		2.0	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	5	8		S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =4A, V _{GS} =10V		0.12	0.16	Ω
	R _{DS(on)} 2	ID=4A, VGS=4V		0.16	0.22	Ω
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		950		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		150		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		30		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		13		ns
Rise Time	tr	See specified Test Circuit		20		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		85		ns
Fall Time	t _f	See specified Test Circuit		55		ns
Diode Forward Voltage	V _{SD}	IS=8A, VGS=0		1.0	1.5	V

Switching Time Test Circuit







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